Additional Experimental Details

Quantitative Hydrogen Yield Measurements: Quantitative H₂ yield measurements were performed in 0.50 M H₂SO₄ in a two-electrode experiment using a two-compartment cell. The two compartments, for the working and counter electrode, respectively, were separated by a Nafion® membrane (Fuelcellstore.com). A graduated cylinder was inverted above the working electrode to collect the H₂(g) produced during the experiment. A constant (cathodic) current of -10 mA was maintained for 50 min (3000 s) on a ~0.2 cm² electrode. The amount of H₂(g) produced was 3.92 mL, as compared to the theoretical yield of 3.92 mL, as calculated with Faraday's law, Dalton's law of partial pressures and the ideal gas law. In a control experiment, a platinum electrode produced an identical quantity of H₂(g) when the same amount of charge was passed through the cathode.

Estimation of turnover frequencies: The turnover frequency was calculated using an established method. First, the density of the sample was calculated using the CoP unit cell. Using the measured BET surface areas, the turnover frequencies are reported as turnovers per second per surface atom, analogous to prior reports for Ni-Mo, Ni₂P, and CoP hollow nanoparticles. The Co and P surface atoms were counted separately.

Calculation of TOF values
- Molar mass: 89.907 g/mol
- Density: 6.416 g/cm³
- Molar Volume: 14.01 mL/mol
- BET Surface Area: 66.5 m²/g
- Current Density at 100 mV overpotential (1 mg cm⁻² loading): ~1.03 × 10⁻² A/cm²
Average surface atoms per 1 square centimeter:

\[
\left( \frac{2 \times 6.022 \times 10^{23} \text{ atoms}}{1 \text{ mol}} \times \frac{1 \text{ mol}}{14.0 \text{ cm}^3} \right)^{2/3} = 2.45 \times 10^{15} \frac{\text{ atoms}}{\text{ cm}^2}
\]

Surface Atoms per tested area at 1 mg/cm²:

\[
\frac{1 \text{ mg}}{1 \text{ cm}^2 (\text{foil})} \times \frac{6.65 \times 10^2 \text{ cm}^2 (\text{particle})}{\text{mg}} \times \frac{2.45 \times 10^{15} \text{ atoms}}{1 \text{ cm}^2 (\text{particle})} = 1.63 \times 10^{18} \frac{\text{ atoms}}{\text{ test} \cdot \text{ cm}^2}
\]

Turnover frequency at -100 mV overpotential (per surface atom):

\[
\frac{1 \text{ turnover}}{2 \text{ e}^-} \times \frac{1.03 \times 10^{-2} A}{1 \text{ cm}^2} \times \frac{1 \text{ mol}}{96485 \text{ C}} \times \frac{6.022 \times 10^{23} \text{ e}^-}{1 \text{ mol}} \times \frac{1 \text{ test} \cdot \text{ cm}^2}{1.65 \times 10^{18} \text{ atoms}}
\]

\[= 0.019 \text{ s}^{-1} \text{ atom}^{-1}\]

Supplementary Figures

**Figure S1.** Representative EDS spectrum of a sample of highly-branched CoP nanostructures. The Co/P ratio was 1/1. The Cu and Si impurities are due to the TEM grid and column, respectively, and were present in control samples of blank TEM grids.
Figure S2. (Left) Powder X-ray diffraction data for a sample of highly branched CoP nanostructures deposited onto Ti foil then annealed at 450 °C under H₂ (5%)/Ar(95%) for 30 min. Simulated XRD patterns for Ti and CoP are shown for comparison. The asterisks indicate a small Co₂P impurity that was observed after annealing. (Right) SEM images of the same sample prior to and after annealing. We did not observe any crystallographic relationships between the interior cores and the branches. It is also difficult to capture the relevant early stages of the reactions that produce the branched CoP nanostructures because of the high temperatures involved.

Figure S3. Three distinct linear sweep voltammograms for hollow, pseudospherical CoP nanoparticles deposited on Ti foil at a loading density of ~0.8 mg cm⁻² in 0.5 M H₂SO₄. The electrodes consistently required an overpotential of -100 mV to produce a current density of -10 mA cm⁻². This value is lower than the overpotential of -117 mV required for the branched CoP nanostructures.
**Figure S4.** (a) Plot of overpotential vs. time, held at -10 mA cm\(^{-2}\) for 18 h, for a Ti foil electrode containing the highly branched CoP nanostructures. (b) Cyclic voltammetric cycles used to simulate the long-term stability of a comparable CoP/Ti electrode in 0.50 M H\(_2\)SO\(_4\) when cycled between +50 mV and -160 mV at a scan rate of 100 mV s\(^{-1}\).

**References**